

Applicant : Isamu Kobori, et al.
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Page : 2 of 8

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Amendments to the Specification

Please replace the title beginning at page 1, line 1 with the following amended title:

“ACTIVE MATRIX CIRCUIT”

Please delete the previous abstract at page 19 and add the following new abstract:

An active matrix circuit comprises a semiconductor layer, and a p-type impurity region provided in said semiconductor layer, and an interlayer insulating film comprising silicon nitride provided over said semiconductor layer.